| PCN Number: | 202 | 20210201000.2 | | | | PCN Date: Fel | | | | eb. 02 2021 | | | |
|--|--|---------------|----------|----------|--|---------------|--------------|------------------|---------|---------------------|--------------------------|------------|--|
| Title: Qualif | ication | of TIF | PI as an | additior | nal a | asseml | oly site for | sel | ect [| Devic | es | | |
| Customer Con | tact: | PCN / | Manager | Dep | t: | | Quality Se | ervic | es | | | | |
| Proposed 1 st 5 | osed 1 st Ship Date: Aug. 1 | | | | 2021 Es t | | | | | | provided at e request | | |
| Change Type: | | | | | | | | | | | • | | |
| | Assembly Site D | | | | | | | | \ | Wafer | r Bump | Site | |
| Assembly F | | | | | | heet | | | | Wafer Bump Material | | | |
| Assembly I | | | | _ | | mber o | change | | | Wafer Bump Process | | | |
| Mechanical | • | | | Test | | | | Ļ | | | Fab S | | |
| Packing/Sh | iipping/ | Label | ing | lest | : Pro | ocess | | - - | | | | laterials | |
| | | | | D.C | -N | Deta | ile | | | warei | r Fab P | rocess | |
| Description of | Chan | 70' | | | <u> </u> | Deta | 113 | | | | | | |
| site for devices | Texas Instruments Incorporated is announcing the qualification of TIPI as an alternate Assembly site for devices listed below in the product affected section. Construction differences and current assembly sites are as follows: | | | | | | | | | | | | |
| | | | | | | TFI | TFME | | | ΓΙΡΙ | | | |
| | Mount | Comp | ound | | | SID# | A-03 | 3 4207123 | | | 3 | | |
| | Mold C | Compo | und | | SID#R-13 | | | | 4222198 | | | | |
| | Bond v | vire, c | liameter | | Au | or Cu | , 1.0mils | Cu, 0.96mils | | | nils | | |
| | Lead F | rame | Prep | | non RLF | | | | RLF | | | | |
| | | | | | | | | | | | | | |
| Reason for Ch | ange: | | | | | | | | | | | | |
| Supply continuity | | | | | | | | | | | | | |
| Anticipated impact on Form, Fit, Function, Quality or Reliability (positive / negative): | | | | | | | | | | | | | |
| None | | | | | | | | | | | | | |
| Anticipated in | npact o | on Ma | terial D | eclara | tior | n | | | | | | | |
| | No Impact to the Material Declaration produreport | | | | rerial Declarations or Product Content reports are driven n production data and will be available following the duction release. Upon production release the revised orts can be obtained at the site link below o://www.ti.com/quality/docs/materialcontentsearch.tsp | | | | | | | | |
| Changes to pr | oduct | ident | ificatio | n resul | tino | g from | this PCN | l: | | | | | |
| Assembly Site | | | | | 1 | | Country Co | | (23L) |) | Asse | embly City | |
| TFME | | | NFM | | CHN | | | | | Development Zone | | | |
| TIPI | | | PHI | | | | PHL | | | | Bag | juio City | |
| Sample product shipping label (not actual product label) | | | | | | | | | | | | | |

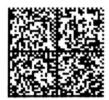
TEXAS INSTRUMENTS

MADE IN: Malaysia 2DC: 2Q:

MSL 2 /260C/1 YEAR SEAL DT MSL 1 /235C/UNLIM 03/29/04

OPT: ITEM:

5A (L)T0:3750



(1P) SN74LS07NSR (Q) 2000 (D) 0336 (31T)LOT: 3959047MLA (4W) TKY(1T) 7523483SI2

(P) (2P) REV:

(2P) REV: (V) 0033317 (20L) CSO: SHE (21L) CCO:USA (22L) ASO: MLA (23L) ACO: MYS

Product Affected:

UCC27517AQDBVRQ1 UCC27518AQDBVRQ1 UCC27519AQDBVRQ1



TI Information Selective Disclosure

Automotive New Product Qualification Summary (As per AEC-Q100 and JEDEC Guidelines)

UCC27517AQDBVRQ1, UCC27518AQDBVRQ1, UCC27519AQDBVRQ1: DBV SOT pkg in TIPI Approved 09-Nov-2020

Product Attributes

| Attributes | Qual Device: UCC27517AQDBVRQ1 | QBS Product Reference: UCC27517AQDBVRQ1 | QBS Product Reference: UCC27519AQDBVRQ1 | QBS Process Reference: TPS2543QRTE | QBS Package Reference: TPS22810TDBVRQ1 |
|------------------------|----------------------------------|--|--|---------------------------------------|---|
| Automotive Grade Level | Grade 1 | Grade 1 | Grade 1 | Grade 1 | Grade 2 |
| Operating Temp Range | -40 to +125 C | -40 to +125 C | -40 to +125 C | -40 to +125 C | -40 to +105 C |
| Product Function | Power Management | Power Management | Power Management | Power Management | Power Management |
| Wafer Fab Supplier | RFAB | RFAB | RFAB | RFAB | RFAB |
| Die Revision | A | A | A | Rev-A_(PG1.0) | A |
| Assembly Site | TIPI | NFME | NFME | CLARK-AT | TIPI |
| Package Type | SOT | SOT | SOT | TQFN | SOT |
| Package Designator | DBV | DBV | DBV | RTE | DBV |
| Ball/Lead Count | 5 | 5 | 5 | 16 | 6 |

⁻ QBS: Qual By Similarity - Qual Device UCC27517AQDBVRQ1 is qualified at LEVEL1-260C

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

| Туре | # | Test Spec | Min Lot | SS/Lot | Test Name / Condition | Duration | Qual Device: UCC27517AQDBVR | QBS Product Reference: | QBS Product Reference: | QBS Process Reference: | QBS Package Reference: |
|-------|--------|---|------------|------------|--|----------------|--------------------------------|---------------------------|---------------------------|---------------------------|---------------------------|
| | Tost C | roup A Ac | Qty | ed Environ | nment Stress Tests | | <u>Q1</u> | UCC27517AQDBVRQ1 | UCC27519AQDBVRQ1 | TPS2543QRTE | TPS22810TDBVRQ1 |
| | lest G | JEDEC | celerat | eu Enviroi | | | | | | | |
| HAST | A2 | JESD22- A110 | 3 | 77 | Biased HAST 130C/85%RH | 96 Hours | = | - | 1/77/0 | 3/231/0 | 3/231/0 |
| AC | А3 | JEDEC JESD22- A102 | 3 | 77 | Autoclave 121C | 96 Hours | - | - | 1/80/0 | 3/237/0 | 3/231/0 |
| TC | A4 | JEDEC JESD22- A104 and Appendix 3 | 3 | 77 | Temperature Cycle, -65/150C | 500 Cycles | 1/77/0 | 1/77/0 | 1/77/0 | 3/231/0 | 3/231/0 |
| TC-BP | A4 | MIL- STD883 Method 2011 | 1 | 60 | Post Temp. Cycle Bond Pull | 500 Cycles | 1/5/0 | 1/5/0 | 1/5/0 | 1/5/0 | 1/5/0 |
| PTC | A5 | JEDEC JESD22- A105 | 1 | 45 | Power Temperature Cycle, -40/125C | 1000 Cycles | N/A | N/A | - | 1/50/0 | 1/45/0 |
| HTSL | A6 | JEDEC JESD22- A103 | 1 | 45 | High Temp Storage Bake 175C | 500 Hours | 1/77/0 | - | 1/45/0 | 3/145/0 | - |
| HTSL | A6 | JEDEC JESD22- A103 | 1 | 45 | High Temp Storage Bake 150C | 1000 Hours | - | - | - | - | 3/135/0 |
| | Test 0 | Group B – Ad | celerat | ed Lifetim | e Simulation Tests | | | | | | |
| HTOL | B1 | JEDEC JESD22- A108 | 3 | 77 | Life Test, 125C | 1000 Hours | - | - | 1/80/0 | - | 3/231/0 |
| HTOL | B1 | JEDEC JESD22- A108 | 3 | 77 | Life Test, 150C | 408 Hours | - | - | - | 3/231/0 | - |
| ELFR | B2 | AEC Q100-008 | 3 | 800 | Early Life Failure Rate, 125C | 48 Hours | - | - | - | - | - |
| ELFR | B2 | AEC Q100-008 | 3 | 800 | Early Life Failure Rate, 150C | 24 Hours | - | - | - | 3/2400/0 | - |
| EDR | В3 | AEC Q100-005 | 3 | 77 | NVM Endurance, Data Retention, and Operational Life | - | N/A | N/A | - | - | - |

| | Tes | t Group C – I | Packa <u>g</u> | e Asse <u>mb</u> | ly Integrity Tests | | | | | | |
|------|-----|--------------------------------------|----------------|------------------|---|---|--|--------|--------|--------|--------|
| WBS | C1 | AEC Q100-001 | 1 | 30 | Wire Bond Shear (Cpk>1.67) | - | 1/30/0 | 1/30/0 | - | 1/30/0 | 1/30/0 |
| WBP | C2 | MIL- STD883 Method 2011 | 1 | 30 | Wire Bond Pull (Cpk>1.67) | - | 1/30/0 | - | - | - | 1/30/0 |
| SD | СЗ | JEDEC JESD22- B102 | 1 | 15 | Surface Mount Solderability | Pb Free and SnPb | 1/15/0 | - | 1/30/0 | 1/30/0 | 1/15/0 |
| PD | C4 | JEDEC JESD22- B100 and B108 | 3 | 10 | Physical Dimensions | Cpk>1.67 | 3/90/0 | 1/30/0 | - | 3/90/0 | 3/30/0 |
| LI | C6 | JEDEC JESD22- B105 | 1 | 50 | Lead Pull | # of leads to destructio n,10 Leads ea. from min. 5 units | 1/50/0 | - | - | - | - |
| | Te | st Group D – | Die Fa | brication | Reliability Tests | | | | | | |
| EM | D1 | JESD61 | - | - | Electromigration | - | Completed Per Process Technology | - | - | - | - |
| | | | | | | | Requirements | | | | |
| TDDB | D2 | JESD35 | - | - | Time Dependant Dielectric Breakdown | - | Requirements Completed Per Process Technology Requirements | - | - | - | - |
| TDDB | D2 | JESD35 JESD60 & 28 | - | - | Dielectric | - | Completed Per Process Technology | - | - | - | - |
| | | JESD60 | | | Dielectric Breakdown Hot Injection | | Completed Per Process Technology Requirements Completed Per Process Technology | - | - | - | - |

| | | Test Group E | – Elec | trical Veri | fication Tests | | | | | | |
|-----|----|-----------------|--------|-------------|----------------------------------|--|--------|--------|--------|--------|--------|
| НВМ | E2 | AEC Q100-002 | 1 | 3 | ESD - HBM - Q100 | 4000 V | - | 1/3/0 | - | 1/3/0 | 1/3/0 |
| CDM | E3 | AEC Q100-011 | 1 | 3 | ESD - CDM - Q100 | 1500 V | 1/3/0 | 1/3/0 | 1/3/0 | 1/3/0 | 1/3/0 |
| LU | E4 | AEC Q100-004 | 1 | 6 | Auto Latch-up | (Per AEC Q100- 004) | - | - | - | 1/6/0 | 1/6/0 |
| LU | E4 | AEC Q100-004 | 1 | 6 | Auto Latch-up | Ta(max) | - | 1/6/0 | - | - | - |
| LU | E4 | AEC Q100-004 | 1 | 6 | Latch-up | (per JESD78) | - | - | 1/6/0 | - | - |
| ED | E5 | AEC Q100-009 | 3 | 30 | Auto Electrical Distributions | Cpk>1.67 Room, hot, and cold test | 3/90/0 | 3/90/0 | 3/90/0 | 3/90/0 | 3/90/0 |

Performed for THB, Biased HAST, AC, uHAST, TC & PTC samples, as applicable

Ambient Operating Temperature by Automotive Grade Level: Grade 0 (or E): -40°C to +150°C Grade 1 (or O): -40°C to +125°C Grade 2 (or T): -40°C to +105°C Grade 3 (or I): -40°C to +85°C

ENTIRE IN LECTURE AT THE PROPERTY OF THE PROPE E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level):

Green/Pb-free Status: Qualified Pb-Free(SMT) and Green

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